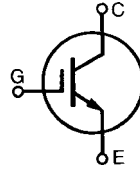


# IGBT

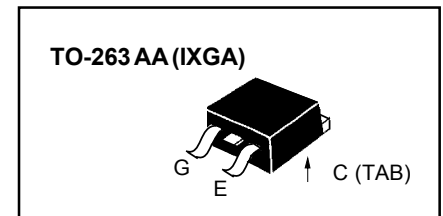
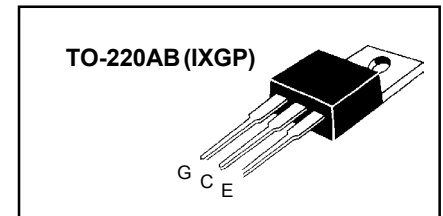
## Lightspeed Series

**IXGA 15N120C**  
**IXGP 15N120C**

$V_{CES} = 1200 \text{ V}$   
 $I_{C25} = 30 \text{ A}$   
 $V_{CE(sat)} = 3.8 \text{ V}$   
 $t_{fi(typ)} = 115 \text{ ns}$



Symbol	Test Conditions	Maximum Ratings	
$V_{CES}$	$T_J = 25^\circ\text{C to } 150^\circ\text{C}$	1200	V
$V_{CGR}$	$T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GE} = 1 \text{ M}\Omega$	1200	V
$V_{GES}$	Continuous	$\pm 20$	V
$V_{GEM}$	Transient	$\pm 30$	V
$I_{C25}$	$T_C = 25^\circ\text{C}$	30	A
$I_{C90}$	$T_C = 90^\circ\text{C}$	15	A
$I_{CM}$	$T_C = 25^\circ\text{C}, 1 \text{ ms}$	60	A
<b>SSOA</b> <b>(RBSOA)</b>	$V_{GE} = 15 \text{ V}, T_{VJ} = 125^\circ\text{C}, R_G = 10 \Omega$ Clamped inductive load	$I_{CM} = 40$ @ $0.8 V_{CES}$	A
$P_C$	$T_C = 25^\circ\text{C}$	150	W
$T_J$		-55 ... +150	$^\circ\text{C}$
$T_{JM}$		150	$^\circ\text{C}$
$T_{stg}$		-55 ... +150	$^\circ\text{C}$
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300	$^\circ\text{C}$
$M_d$	Mounting torque with screw M3 Mounting torque with screw M3.5	0.45/4 0.55/5	Nm/lb.in.
<b>Weight</b>	TO-220 TO-263	4 2	g



### Features

- International standard packages JEDEC TO-220AB and TO-263AA
- Low switching losses
- MOS Gate turn-on - drive simplicity

### Applications

- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies

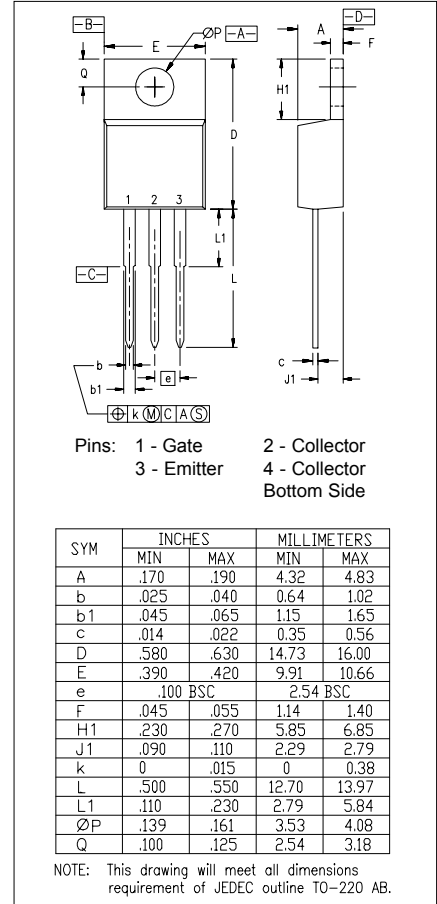
### Advantages

- Easy to mount with one screw
- Reduces assembly time and cost
- High power density

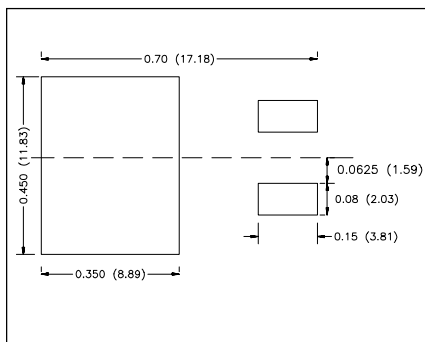
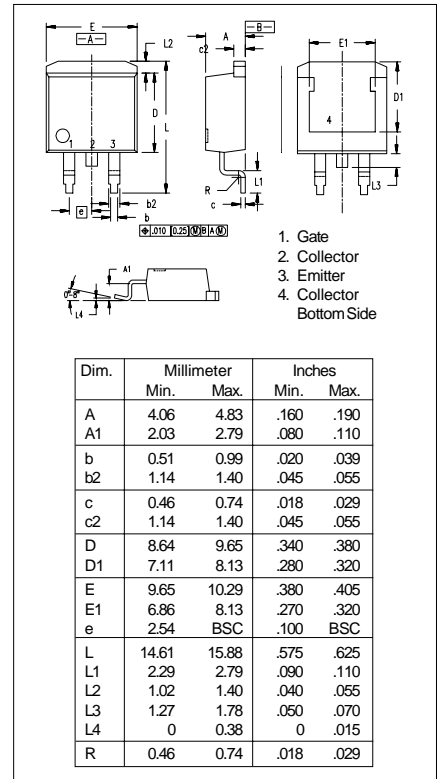
Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)	Characteristic Values		
		Min.	Typ.	Max.
$BV_{CES}$	$I_C = 250 \mu\text{A}, V_{GE} = 0 \text{ V}$	1200		V
$V_{GE(th)}$	$I_C = 250 \mu\text{A}, V_{CE} = V_{GE}$	2.5		V
$I_{CES}$	$V_{CE} = V_{CES}$ $V_{GE} = 0 \text{ V}$			100 $\mu\text{A}$ 3.5 mA
	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$			
$I_{GES}$	$V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$			$\pm 100 \text{ nA}$
$V_{CE(sat)}$	$I_C = I_{C90}, V_{GE} = 15$ $T_J = 125^\circ\text{C}$			3.8 V
			3.0	V

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)	Characteristic Values			
		Min.	Typ.	Max.	
$g_{fs}$	$I_C = I_{C90}, V_{CE} = 10\text{ V}$ , Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $\leq 2\%$	12	15	S	
$C_{ies}$	$V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$		1720	pF	
$C_{oes}$			95	pF	
$C_{res}$			35	pF	
$Q_g$	$I_C = I_{C90}, V_{GE} = 15\text{ V}, V_{CE} = 0.5\text{ V}_{CES}$		69	nC	
$Q_{ge}$			13	nC	
$Q_{gc}$			26	nC	
$t_{d(on)}$	<b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b> $I_C = I_{C90}, V_{GE} = 15\text{ V}$ $V_{CE} = 960\text{ V}, R_G = R_{off} = 10\ \Omega$ Remarks: Switching times may increase for $V_{CE}$ (Clamp) $> 0.8\text{ V}_{CES}$ , higher $T_J$ or increased $R_G$		25	ns	
$t_{ri}$			15	ns	
$t_{d(off)}$			150	200	ns
$t_{fi}$			115	190	ns
$E_{off}$			1.05	1.6	mJ
$t_{d(on)}$	<b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b> $I_C = I_{C90}, V_{GE} = 15\text{ V}$ $V_{CE} = 960\text{ V}, R_G = R_{off} = 10\ \Omega$ Remarks: Switching times may increase for $V_{CE}$ (Clamp) $> 0.8\text{ V}_{CES}$ , higher $T_J$ or increased $R_G$		25	ns	
$t_{ri}$			18	ns	
$E_{on}$			0.60	mJ	
$t_{d(off)}$			220	ns	
$t_{fi}$			250	ns	
$E_{off}$		2.1	mJ		
$R_{thJC}$			0.83	K/W	
$R_{thCK}$	TO-220	0.5		K/W	

### TO-220 AB Dimensions



### TO-263 AA Outline



### Min. Recommended Footprint (Dimensions in inches and mm)

IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

4,835,592    4,881,106    5,017,508  
4,850,072    4,931,844    5,034,796

5,049,961    5,187,117  
5,063,307    5,237,481

5,486,715    6,306,228B1  
5,381,633